

PH770DBR 770nm Series

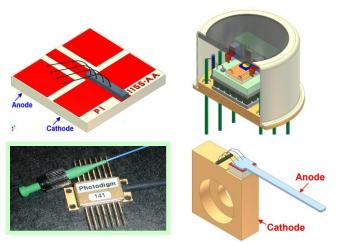
High-Power Single-Frequency Laser Diode

Technology

- DBR Single-Frequency Laser Chip
- AlGaAs QW Active Layer
- Epi designed for high reliability

Features

- Available in several package styles
- Pulsed operation for spectral stability at short pulse lengths
- High power for CW applications
- High Slope Efficiency



Description

The PH770DBR Series of high-power edge-emitting lasers are based on Photodigm's advanced singlefrequency laser technology. It provides a diffraction limited, single lateral and longitudinal mode beam. Facets are passivated for high-power reliability. Applications include spectroscopy for potassium-based application.

Absolute Maximum Ratings

Parameter	Symbol	Unit	Min	Max
Storage Temperature	T _{STG}	С°	0	80
Operating Temperature	T _{OP}	С°	5.0	70
CW Laser Forward Current, T=Top	I _F	mA	-	150**
Pulsed Laser Forward Current, T=25°C, PW=300 ns, DC=10%	I _F	А	-	0.3
Laser Reverse Voltage	V _R	V	-	0.0
Photodiode Forward Current <u>1/2/</u>	I _P	mA	-	5.0
Photodiode Reverse Voltage <u>1/2/</u>	V _R	V	-	20.0
Photodiode Dark Current, V _R =10V, LD I _F =0, <u>1/2/</u>	I _D	nA	-	50
TEC Current <u>1/2/</u>	I _{TEC}	Α	-2.0	2.0
TEC Voltage <u>1/2/</u>	V _{TEC}	V	-6.0	6.0
Thermistor Current <u>1/2/</u>	I _{THRM}	mA	-	1.0
Thermistor Voltage <u>1/2/</u>	V _{THRM}	V	-	10
External Back Reflection	-	dB	-	-14
Lead Soldering Temperature, 10 sec. Max. <u>1/2</u> /	-	°C	-	260
Fiber Pull Force <u>1</u> /	-	N	-	5.0
Fiber Bend Radius <u>1</u> /	-	mm	-	35

1/ Butterfly package 2/ TO8 package** Do not exceed drive current or operating power of supplied LIV**



PRODUCT BULLETIN

CW Characteristics at T _c = 25 C unless otherwise specified								
Parameter	Symbol	Unit	Min	Тур	Max			
Center Wavelength	λ_{c}	nm	768	770	772			
Optical Output Power @ LIV Currrent	Po	mW	See Power Options Call-out					
Slope Efficiency, <u>1</u> /	η_{d}	W/A	0.25	0.36				
Slope Efficiency	η_{d}	W/A	0.60	0.75	-			
Threshold Current	l _{th}	mA	-	50	70			
Laser Series Resistance	Rs	Ω	-	2.0	2.5			
Laser Forward Voltage	V _F	V	-	2.0	2.5			
Thermistor Resistance @ 25°C, 1/2/	R _T	KΩ	-	10	-			
Photodiode Dark Current, V _R =10V, LD I _F =0, 1/2/	I _D	nA	-	-	50			
Laser Line Width	Δv	MHz	-	0.7	1.0			
Polarization Extinction Ratio, <u>1</u> /	PER	dB	-16	-19	-			
Beam Divergence @ FWHM	θιι Χ θ⊥	0	-	6 X 26	8 X 28			
Side Mode Suppression Ratio	SMSR	dB	-30	-	-			
Laser Polarization				TE				
Mode Structure			Fundamental Mode					
Mode Structure			Fundamental Mode					

CW Characteristics at T_c = 25°C unless otherwise specified

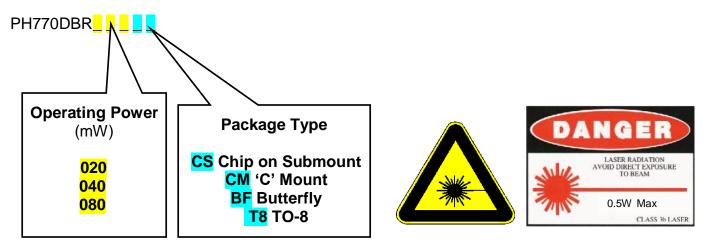
1/Butterfly package 2/TO-8 package

Handling Precautions

These devices are sensitive to ESD. When handling the module, grounded work area and wrist strap must be used. Always store in an antistatic container with all leads shorted together.

How To Order

Part number example: PH770DBR080CM. Assign optical power from those shown below. Use a three-digit format for all power entries. Call factory for special performance selection and certification to certain atomic absorption lines. Butterfly package is offered at 20mW operating power only and is not recommended for Spectroscopy applications. (see application note titled Optical Feedback)



Photodigm, Inc. reserves the right to make changes in design, specifications and other information at any time, and without prior notice. The information contained within the product bulletin is believed to be accurate. However, no responsibility is assumed for possible inaccuracy or omission. Any information contained herein shall legally bind Photodigm, Inc. only if it is specifically incorporated in the terms and conditions of a sales agreement.

www.photodigm.com

1155 E. Collins Blvd. #200, Richardson, TX 75081

Phone: 972-235-7584 Pa

Page 2 of 2